NSN 5961-01-466-0295

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-466-0295 **Inclosure Material:** Glass **Overall Length:** 12.000 millimeters **Terminal Length:** 2.750 millimeters **Overall Width:** 0.150 millimeters **End Application:** General purpose test equipment **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 breakdown voltage, collector to emitter, sustained and 50.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 250.0 milliwatts small-signal output power, common-base preset **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** Uhf/microwave pnp bjt **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No